

# RCD051N20

### Nch 200V 5.0A Power MOSFET

$V_{DSS}$	200V
R <sub>DS(on)</sub> (Max.)	$760 \text{m}\Omega$
I <sub>D</sub>	5.0A
$P_D$	29W

### Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Drive circuits can be simple.
- 4) Parallel use is easy.
- 5) Pb-free lead plating; RoHS compliant
- 6) 100% Avalanche tested

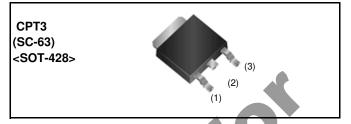
## Application

**Switching Power Supply** 

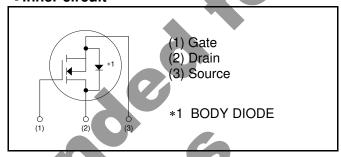
**Automotive Motor Drive** 

Automotive Solenoid Drive

### Outline



### •Inner circuit



### Packaging specifications

Ti dond	ging specifications	
	Packaging	Taping
	Reel size (mm)	330
Typo	Tape width (mm)	16
Type	Basic ordering unit (pcs)	2,500
	Taping code	TL
	Marking	C51N20

# • Absolute maximum ratings $(T_a = 25^{\circ}C)$

Paramet	er	Symbol	Value	Unit
Drain - Source voltage		V <sub>DSS</sub>	200	V
Continuous drain current	I <sub>D</sub> *1	±5.0	А	
Continuous drain current	T <sub>c</sub> = 100°C	I <sub>D</sub> *1	±2.7	А
Pulsed drain current		I <sub>D,pulse</sub> *2	±20	А
Gate - Source voltage		$V_{GSS}$	±30	V
Avalanche energy, single puls	е	E <sub>AS</sub> *3	1.83	mJ
Avalanche current		I <sub>AR</sub> *3	2.5	А
Dower dissination	T <sub>c</sub> = 25°C	P <sub>D</sub>	29	W
Power dissipation	$T_a = 25^{\circ}C^{*4}$	P <sub>D</sub>	0.85	W
Junction temperature		T <sub>j</sub>	150	°C
Range of storage temperature	)	T <sub>stg</sub>	-55 to +150	°C

### ●Thermal resistance

Parameter	Symbol	Values			Unit
Farameter	Symbol	Min.	Тур.	Max.	Offic
Thermal resistance, junction - case	$R_{thJC}$	-	-	4.3	°C/W
Thermal resistance, junction - ambient *4	$R_{thJA}$	-	-	147	°C/W
Soldering temperature, wavesoldering for 10s	T <sub>sold</sub>	1	1	265	°C

# ●Electrical characteristics(T<sub>a</sub> = 25°C)

Parameter	Cumbal	Symbol Conditions -		Values		
Farameter	Syllibol	Conditions	Min.	Тур.	Max.	Unit
Drain - Source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V$ , $I_D = 1mA$	200	-	-	V
Zoro gato voltago drain current	la ca	$V_{DS} = 200V, V_{GS} = 0V$ $T_j = 25^{\circ}C$	-	3	10	^
Zero gate voltage drain current	I <sub>DSS</sub>	$V_{DS} = 200V, V_{GS} = 0V$ $T_j = 125^{\circ}C$		-	100	μΑ
Gate - Source leakage current	I <sub>GSS</sub>	$V_{GS} = \pm 30V, V_{DS} = 0V$	-	-	±100	nA
Gate threshold voltage	V <sub>GS (th)</sub>	$V_{DS} = 10V$ , $I_D = 1mA$	3.25	-	5.25	V
		$V_{GS} = 10V, I_D = 2.5A$	-	540	760	
Static drain - source on - state resistance	R <sub>DS(on)</sub> *5	$V_{GS} = 10V, I_D = 2.5A$ $T_j = 125^{\circ}C$	-	785	1100	mΩ
Forward transfer admittance	g <sub>fs</sub>	$V_{DS} = 10V, I_D = 2.5A$	1.3	2.6	-	S



# •Electrical characteristics( $T_a = 25$ °C)

Parameter	Cumbal	Conditions	Values			Unit
- rarameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Input capacitance	C <sub>iss</sub>	$V_{GS} = 0V$	-	330	-	
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 25V	-	33	-	pF
Reverse transfer capacitance	$C_{rss}$	f = 1MHz	-	15		
Turn - on delay time	$t_{d(on)}^{*5}$	$V_{DD} \simeq 100V, V_{GS} = 10V$	-	13		
Rise time	t <sub>r</sub> *5	$I_{D} = 2.5A$	-	15	-	no
Turn - off delay time	t <sub>d(off)</sub> *5	$R_L = 40.2\Omega$	- (	18	-	ns
Fall time	t <sub>f</sub> *5	$R_G = 10\Omega$		8	-	

# •Gate Charge characteristics( $T_a = 25$ °C)

Parameter	Symbol	mbol Conditions		Values		
r arameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Total gate charge	$Q_g^{*5}$	V <sub>DD</sub> ≃ 100V		8.3	-	
Gate - Source charge	Q <sub>gs</sub> *5	$I_{D} = 5.0A$	_	3.3	-	nC
Gate - Drain charge	Q <sub>gd</sub> *5	V <sub>GS</sub> = 10V	-	3.2	-	
Gate plateau voltage	V <sub>(plateau)</sub>	$V_{DD} \approx 100V, I_D = 5.0A$	-	7.4	-	V

# ●Body diode electrical characteristics (Source-Drain)(T<sub>a</sub> = 25°C)

Parameter	Symbol Conditions -		Values			Unit
1 aranieter	Syllidoi	Conditions	Min.	Тур.	Max.	Offic
Continuous source current	l <sub>S</sub> *1	T <sub>c</sub> = 25°C	-	ı	5.0	Α
Pulsed source current	I <sub>SM</sub> *2	1 <sub>c</sub> = 25 0	ı	ı	20	Α
Forward voltage	$V_{SD}^{*5}$	$V_{GS} = 0V, I_S = 5.0A$	ı	ı	1.5	V
Reverse recovery time	t <sub>rr</sub> *5	I <sub>S</sub> = 2.5A	-	75	ı	ns
Reverse recovery charge	Q <sub>rr</sub> *5	di/dt = 100A/μs	-	150	-	nC

<sup>\*1</sup> Limited only by maximum temperature allowed.

<sup>\*2</sup> Pw  $\leq$  10 $\mu$ s, Duty cycle  $\leq$  1%

<sup>\*3</sup> L  $^{\simeq}$  500 $\mu$ H,  $V_{DD}$  = 50V, Rg = 25 $\Omega$ , starting  $T_j$  = 25°C

<sup>\*4</sup> Mounted on a epoxy PCB FR4 (20mm × 20mm × 0.8mm)

<sup>\*5</sup> Pulsed

Fig.1 Power Dissipation Derating Curve

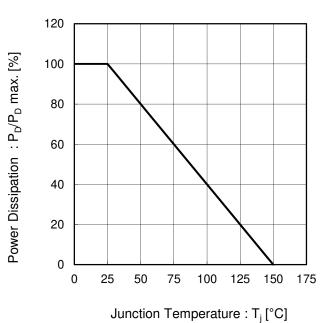
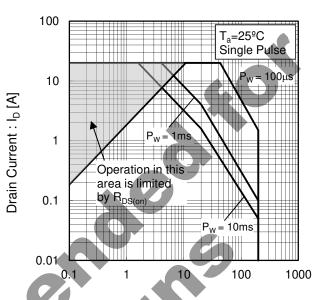
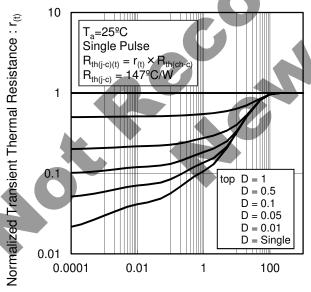


Fig.2 Maximum Safe Operating Area



Drain - Source Voltage : V<sub>DS</sub> [V]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width



Pulse Width: Pw[s]

Fig.4 Avalanche Current vs Inductive Load

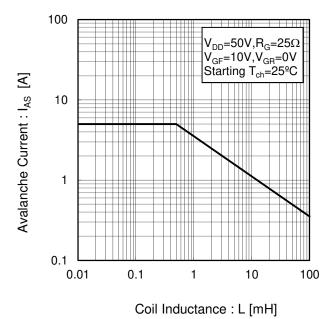
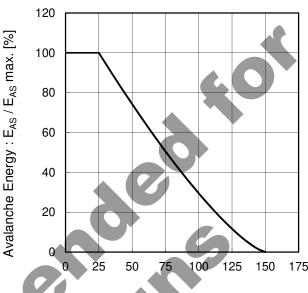
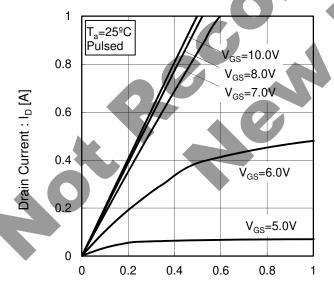


Fig.5 Avalanche Energy Derating Curve vs Junction Temperature



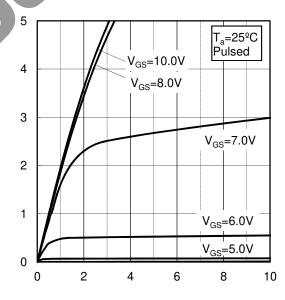
Junction Temperature : T<sub>i</sub> [°C]

Fig.6 Typical Output Characteristics(I)



Drain - Source Voltage : V<sub>DS</sub> [V]

Fig.7 Typical Output Characteristics(II)



Drain - Source Voltage : V<sub>DS</sub> [V]

Drain Current : I<sub>D</sub> [A]

Fig.8 Breakdown Voltage vs. Junction Temperature

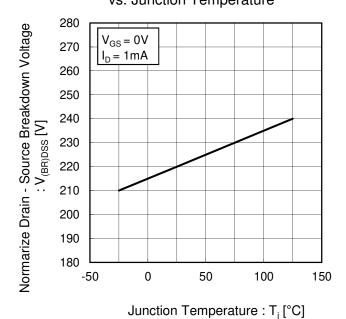
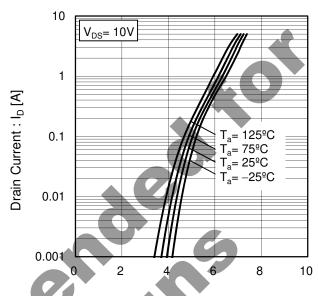


Fig.9 Typical Transfer Characteristics



Gate - Source Voltage :  $V_{GS}[V]$ 

Fig.10 Gate Threshold Voltage vs. Junction Temperature

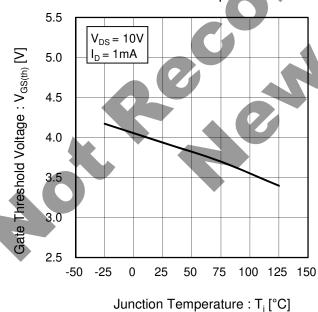
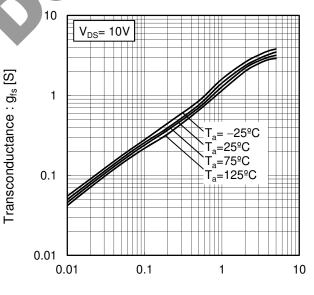
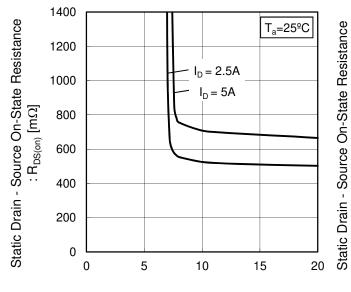


Fig.11 Transconductance vs. Drain Current



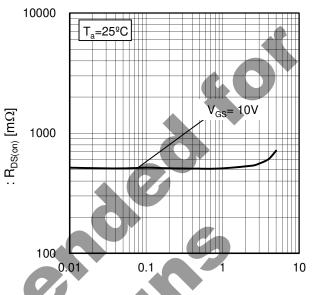
Drain Current : I<sub>D</sub> [A]

Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage



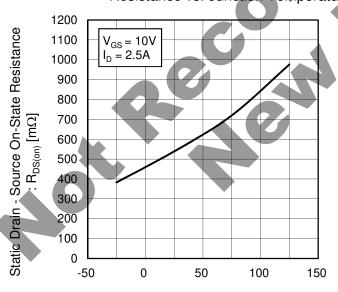
Gate - Source Voltage : V<sub>GS</sub> [V]

Fig.13 Static Drain - Source On - State Resistance vs. Drain Current(I)



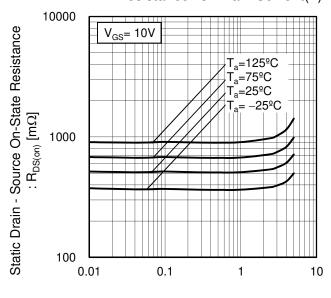
Drain Current : I<sub>D</sub> [A]

Fig.14 Static Drain - Source On - State
Resistance vs. Junction Temperature



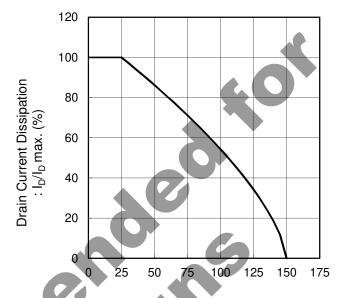
Junction Temperature : T<sub>i</sub> [ºC]

Fig.15 Static Drain - Source On - State Resistance vs. Drain Current(II)



Drain Current : I<sub>D</sub> [A]

Fig.16 Drain Current Derating Curve



Junction Temperature : T<sub>i</sub> [°C]

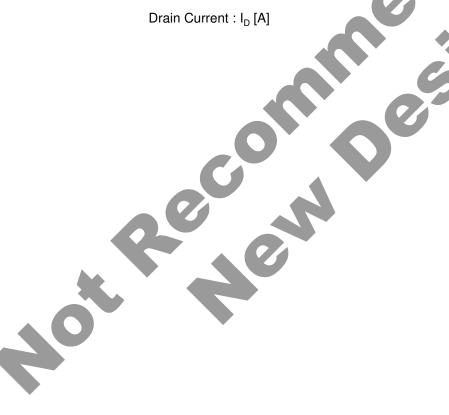
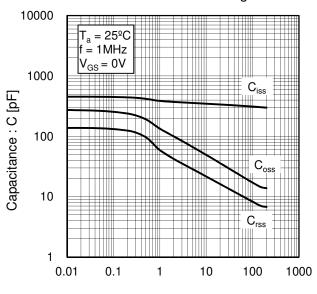
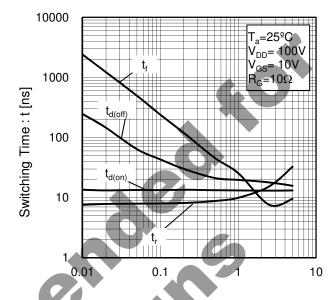


Fig.17 Typical Capacitance vs. Drain - Source Voltage



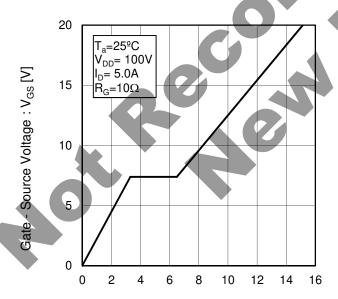
Drain - Source Voltage :  $V_{DS}$  [V]

Fig.18 Switching Characteristics

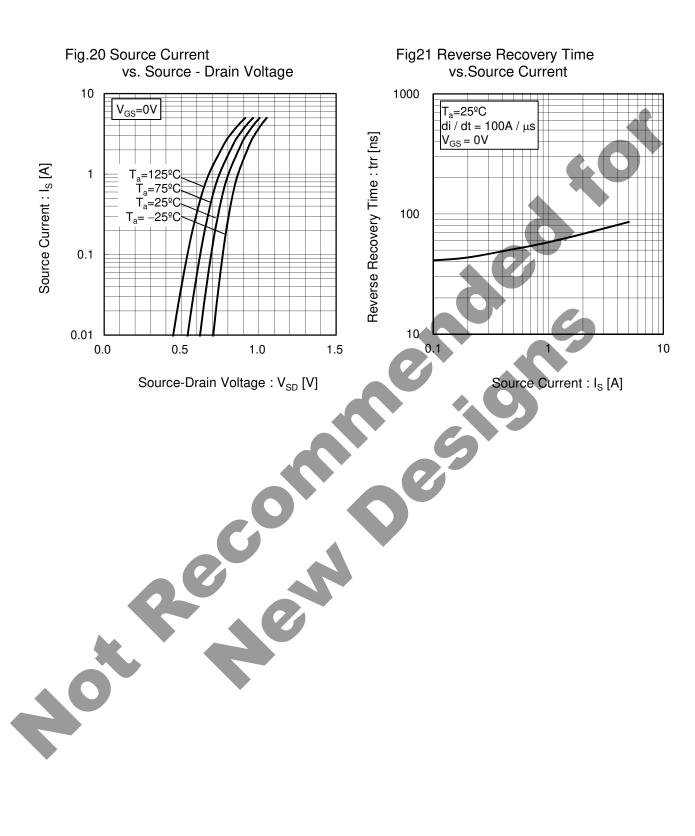


Drain Current : I<sub>D</sub> [A]

Fig.19 Dynamic Input Characteristics



Total Gate Charge :  $Q_g$  [nC]



### Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

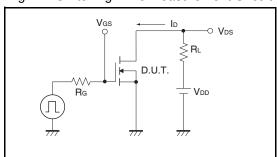


Fig.2-1 Gate Charge Measurement Circuit

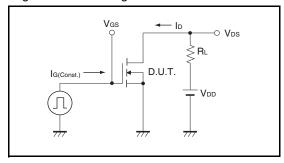


Fig.3-1 Avalanche Measurement Circuit

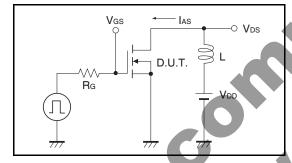


Fig.1-2 Switching Waveforms

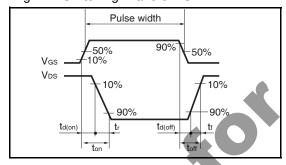


Fig.2-2 Gate Charge Waveform

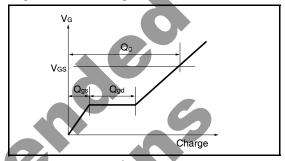
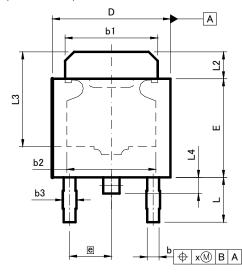


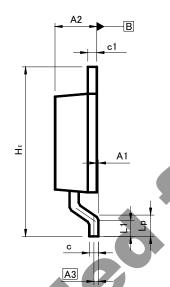
Fig.3-2 Avalanche Waveform

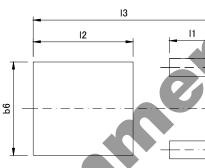


# ●Dimensions (Unit:mm)









DIM	MILIM	ETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
A1	0.00	0.15	0	0.006	
A2	2,20	2.50	0.087	0.098	
A3	0.:	25	0.0	01	
b	0.55	0.75	0.022	0.03	
b1	5.00	5.30	0.197	0.209	
b2	5.0	00	0.3	20	
b3	0.	75	0.0	03	
С	0.40	0.60	0.016	0.024	
c1	0.40	0.60	0.016	0.024	
D	6.30	6.70	0.248	0.264	
E	5.40	5.80	0.213	0.228	
е	2.3	30	0.09		
HE	9.00	10.00	0.354	0.394	
L	2.20	2.80	0.087	0.11	
L1	0.80	1.40	0.031	0.055	
L2	1.20	1.80	0.047	0.071	
L3	5.30		0.209		
L4	0.9	0.90		35	
Lp	1.00	1.60	0.039	0.063	
х	_	0.25	_	0.01	

DIM	MILIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
b5	_	1.00	ı	0.04	
b6	_	5.20	-	0.205	
11	-	2.50	ı	0.098	
12	-	5.50	ı	0.217	
13	_	10.00	_	0.394	

Dimension in mm/inches

Rev.003

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CLASSⅢ	CL ACCTI	CLASS II b	CLACCIII
CLASSIV	CLASSⅢ	CLASSⅢ	CLASSII

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  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power, exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
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  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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